

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		Vdss	100	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	T _A = +25°C T _A = +70°C	lD	7.4 5.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	45	A
Maximum Continuous Body Diode Forward Current (Note 6)		ls	3.2	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Ism	45	A
Avalanche Current, L = 0.1mH		las	25	A
Avalanche Energy, L = 0.1mH		Eas	31.25	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	91	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.9	W
Thermal Resistance, Junction to Ambient (Note 6)		R _{0JA}	65	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	12.9	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	8.5	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

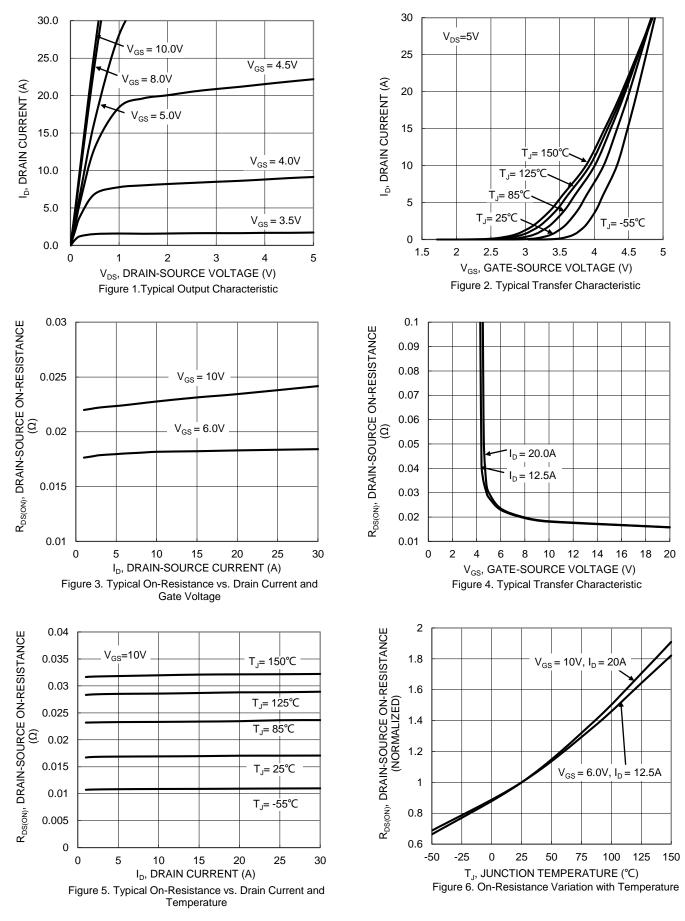
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				1		
Drain-Source Breakdown Voltage	BVDSS	100	—	_	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 80V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	2	—	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
		_	17	23	mΩ	$V_{GS} = 10V, I_D = 20A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	22	30		VGS = 6V, ID = 12.5A
Diode Forward Voltage	Vsd		0.9	1.2	V	V _{GS} = 0V, I _S = 20A
DYNAMIC CHARACTERISTICS (Note 8)	•					·
Input Capacitance	Ciss	—	1544		pF	V _{DS} = 50V, V _{GS} = 0V, f = 1MHz
Output Capacitance	Coss	_	250	_		
Reverse Transfer Capacitance	Crss	_	20.4	_		
Gate Resistance	Rg	_	1.26	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 10V)	Qg	_	21.4	_		V _{DD} = 50V, I _D = 20A
Total Gate Charge (V _{GS} = 6V)	Qg	_	13.4	_	nC	
Gate-Source Charge	Qgs	_	4.6	_	nc	
Gate-Drain Charge	Q _{gd}	_	6.0	—		
Turn-On Delay Time	tD(ON)		8.2			$V_{DD} = 50V, V_{GS} = 10V,$ $I_D = 20A, R_g = 11\Omega$
Turn-On Rise Time	tR	_	11.2	_		
Turn-Off Delay Time	t _{D(OFF)}		27.5	—	ns	
Turn-Off Fall Time	tF		13.7	—		
Body Diode Reverse Recovery Time	t _{RR}		37.5	—	ns	- I _F = 20A, di/dt = 100A/μs
Body Diode Reverse Recovery Charge	Qrr	_	50.9	—	nC	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to product testing.



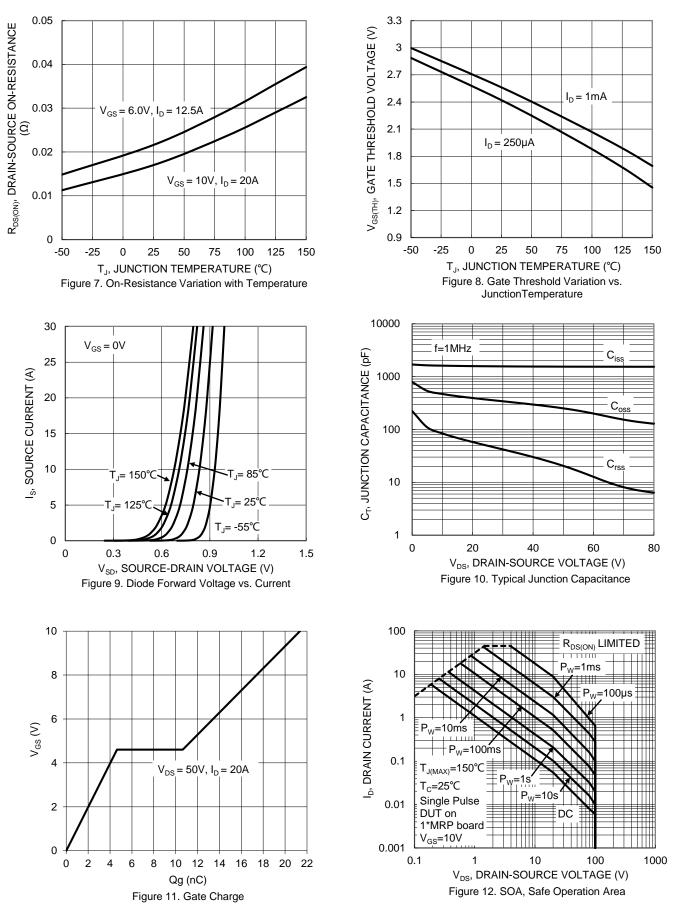
DMT10H025SSS



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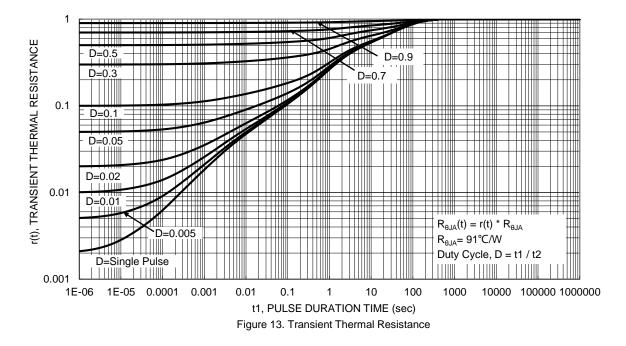


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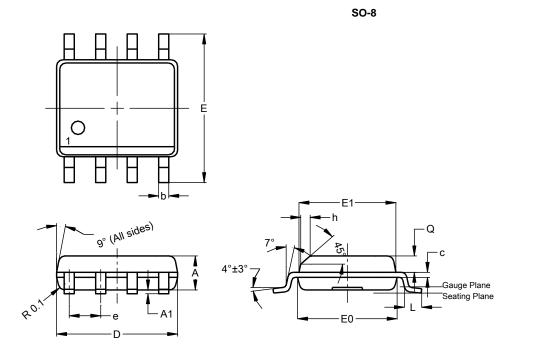






Package Outline Dimensions

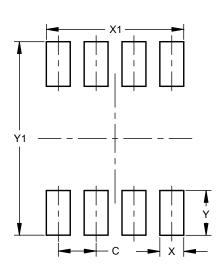
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SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h			0.35		
L	0.62	0.82	0.72		
q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
C	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

SO-8



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